

**Vishay Semiconductors** 

### ADD-A-PAK Generation VII Power Modules Thyristor/Diode and Thyristor/Thyristor, 75 A



ADD-A-PAK

PRODUCT SUMMARY					
$I_{T(AV)}$ or $I_{F(AV)}$	75 A				

#### **MECHANICAL DESCRIPTION**

The ADD-A-PAK Generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

#### **FEATURES**

- High voltage
- Industrial standard package
- · Low thermal resistance
- UL approved file E78996 😱
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

#### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

#### **ELECTRICAL DESCRIPTION**

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I <sub>T(AV)</sub> or I <sub>F(AV)</sub>	85 °C	75					
I <sub>O(RMS)</sub>	As AC switch	165	۸				
I <sub>TSM,</sub>	50 Hz	1300	A				
I <sub>FSM</sub>	60 Hz	1360					
l <sup>2</sup> t	50 Hz	8.45	kA <sup>2</sup> s				
	60 Hz	7.68	KA-S				
l²√t		84.5	kA²√s				
V <sub>RRM</sub>	Range	400 to 1600	V				
T <sub>Stg</sub>		- 40 to 125	°C				
TJ		- 40 10 125	U				



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ELECTRICAL SPECIFICATIONS

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VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK OFF-STATE VOLTAGE, GATE OPEN CIRCUIT V	I <sub>RRM,</sub> I <sub>DRM</sub> AT 125 °C mA		
	04	400	500	400			
06	06	600	700	600			
	08	800	900	800			
VSK.71	10	1000	1100	1000	15		
	12	1200	1300	1200			
14		1400	1500	1400			
	16	1600	1700	1600			

ADD-A-PAK Generation VII Power Modules

Thyristor/Diode and Thyristor/Thyristor, 75 A

PARAMETER	SYMBOL		VALUES	UNITS			
Maximum average on-state current (thyristors)	I <sub>T(AV)</sub>	180° conductio	180° conduction, half sine wave,				
Maximum average forward current (diodes)	I <sub>F(AV)</sub>	T <sub>C</sub> = 85 °C					
Maximum continuous RMS on-state current, as AC switch	I <sub>O(RMS)</sub>		or or I <sub>(RMS)</sub>				
		t = 10 ms	No voltage		1300	A	
Maximum peak, one-cycle non-repetitive	ITSM	t = 8.3 ms	reapplied	Sinusoidal	1360		
on-state or forward current	or I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>	half wave, initial T <sub>J</sub> = T <sub>J</sub> maximum	1093		
	1 3101	t = 8.3 ms	reapplied		1140		
Maximum I <sup>2</sup> t for fusing		t = 10 ms	No voltage		8.45	kA <sup>2</sup> s	
	l <sup>2</sup> t	t = 8.3 ms	reapplied	Initial T <sub>J</sub> = T <sub>J</sub> maximum	7.68		
		t = 10 ms	100 % V <sub>RRM</sub>		5.97		
		t = 8.3 ms	reapplied		5.45		
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t <sup>(1)</sup>	t = 0.1 ms to 1 T <sub>J</sub> = T <sub>J</sub> maxim	84.5	kA²√s			
Markey and a sufficient state of the second	V <sub>T(TO)</sub> <sup>(2)</sup>	Low level (3)	<b>T T D D</b>		0.96		
Maximum value or threshold voltage		High level <sup>(4)</sup>	$T_J = T_J maxin$	1.08	V		
Maximum value of on-state	. (2)	Low level (3)	·		3.28		
slope resistance	r <sub>t</sub> <sup>(2)</sup>	High level <sup>(4)</sup>	$T_J = T_J maxin$	2.86	mΩ		
Maximum neek on atota ay famuard valtage	V <sub>TM</sub>	$I_{TM} = \pi \times I_{T(AV)}$	T 05 %C	1.72	V		
Maximum peak on-state or forward voltage	V <sub>FM</sub>	$I_{FM} = \pi \times I_{F(AV)}$					
Maximum non-repetitive rate of rise of turned on current	dl/dt		$\begin{split} T_J &= 25 \ ^{\circ}C, \ from \ 0.67 \ V_{DRM}, \\ I_{TM} &= \pi \ x \ I_{T(AV)}, \ I_g &= 500 \ mA, \ t_r < 0.5 \ \mu s, \ t_p > 6 \ \mu s \end{split}$				
Maximum holding current	Ι <sub>Η</sub>	T <sub>J</sub> = 25 °C, and resistive load,	250	mA			
Maximum latching current	١L		$T_{J} = 25 \text{ °C}$ , anode supply = 6 V, resistive load				

#### Notes

<sup>(1)</sup> I<sup>2</sup>t for time  $t_x = I^2 \sqrt{t} x \sqrt{t_x}$ 

<sup>(2)</sup> Average power =  $V_{T(TO)} \times I_{T(AV)} + r_t \times (I_{T(RMS)})^2$ 

<sup>(3)</sup> 16.7 % x  $\pi$  x  $I_{AV} < I < \pi$  x  $I_{AV}$ 

(4)  $I > \pi \times I_{AV}$ 

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TRIGGERING					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>			12	W
Maximum average gate power	P <sub>G(AV)</sub>			3.0	vv
Maximum peak gate current	I <sub>GM</sub>			3.0	А
Maximum peak negative gate voltage	e - V <sub>GM</sub>		10		
	V <sub>GT</sub>	T <sub>J</sub> = - 40 °C	Anode supply = 6 V resistive load	4.0	V
Maximum gate voltage required to trigger		T <sub>J</sub> = 25 °C		2.5	
		T <sub>J</sub> = 125 °C		1.7	
	I <sub>GT</sub>	T <sub>J</sub> = - 40 °C		270	
Maximum gate current required to trigger		T <sub>J</sub> = 25 °C	Anode supply = 6 V resistive load	150	mA
		T <sub>J</sub> = 125 °C		80	
Maximum gate voltage that will not trigger	V <sub>GD</sub>	T <sub>J</sub> = 125 °C, rated V <sub>DRM</sub> applied		0.25	V
Maximum gate current that will not trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, rated V <sub>DRM</sub> applied		6	mA

BLOCKING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak reverse and off-state leakage current at V <sub>RRM</sub> , V <sub>DRM</sub>	I <sub>RRM,</sub> I <sub>DRM</sub>	T <sub>J</sub> = 125 °C, gate open circuit	15	mA				
Maximum RMS insulation voltage	V <sub>INS</sub>	50 Hz	3000 (1 min) 3600 (1 s)	V				
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = 125 \text{ °C}$ , linear to 0.67 $V_{DRM}$	1000	V/µs				

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Junction operating and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 125	°C	
Maximum internal thermal resistance, junction to case per leg Typical thermal resistance, case to heatsink per module		R <sub>thJC</sub>	DC operation	0.29		
		R <sub>thCS</sub>	CS Mounting surface flat, smooth and greased		°C/W	
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of	4	Nm	
	busbar		3 hours to allow for the spread of the compound.	3	INIT	
Approximate weight				75	g	
Approximate weight				2.7	oz.	
Case style			JEDEC	TO-240AA	compatible	

DEVICES	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.71	0.052	0.062	0.079	0.116	0.197	0.037	0.064	0.085	0.121	0.200	°C/W

Note

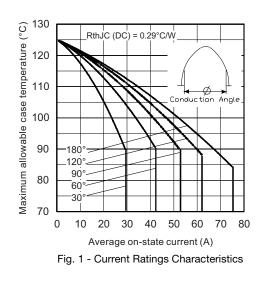
Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC

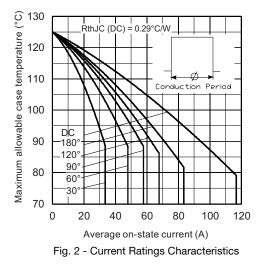
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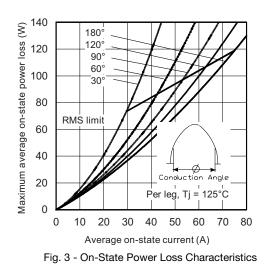
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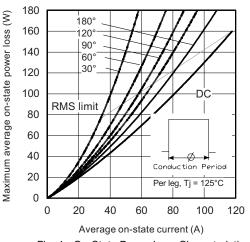
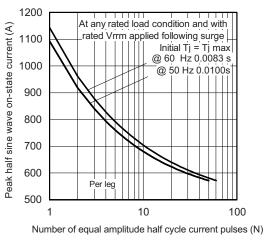
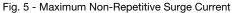


Fig. 4 - On-State Power Loss Characteristics





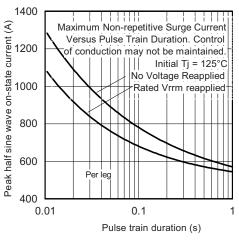


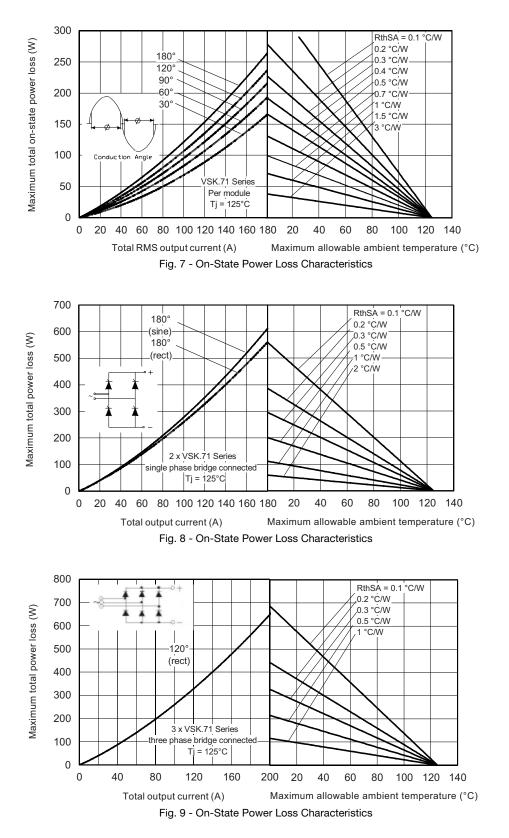
Fig. 6 - Maximum Non-Repetitive Surge Current

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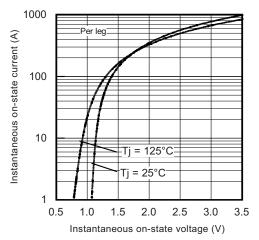
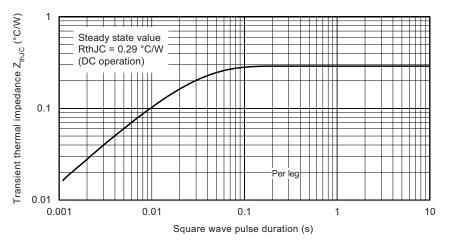
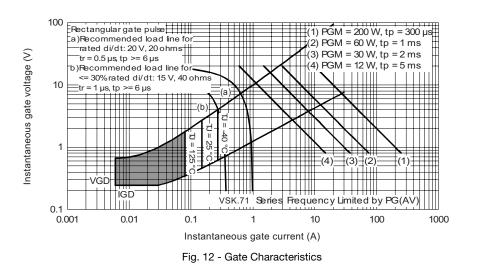


Fig. 10 - On-State Voltage Drop Characteristics







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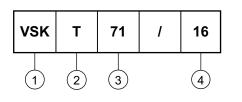
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#### **ORDERING INFORMATION TABLE**

**CIRCUIT CONFIGURATION** 

Downloaded from Elcodis.com electronic components distributor

Device code



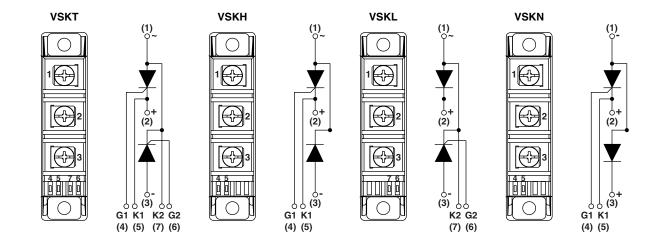
1 - Module type

2

- Circuit configuration (see end of datasheet)
- 3 Current code (75 A)
- 4 Voltage code (see Voltage Ratings table)

#### Note

• To order the optional hardware go to www.vishay.com/doc?95172



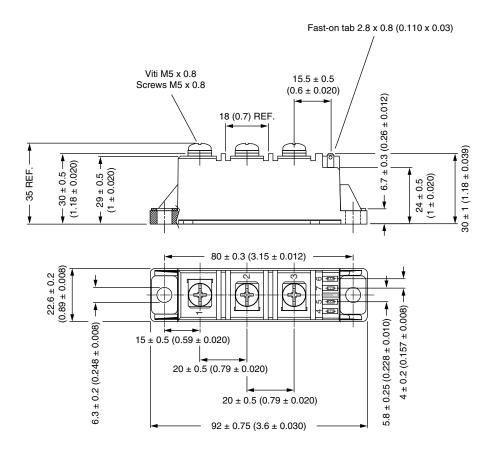
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95368				

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## **ADD-A-PAK Generation VII - Thyristor**

**DIMENSIONS** in millimeters (inches)

SHA





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